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50 MHz to 4000 MHz ACTIVE BIAS SILICON **GERMANIUM CASCADABLE GAIN BLOCK**

Package: SOT-86

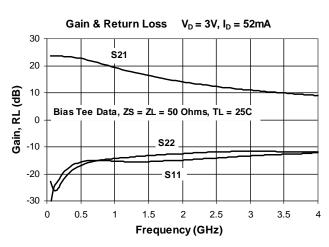




Product Description

RFMD's SGC4486Z is a high performance SiGe HBT MMIC amplifier utilizing a Darlington configuration with a patented active bias network. The active bias network provides stable current over temperature and process Beta variations. Designed to run directly from a 3V supply, the SGC4486Z does not require a dropping resistor as compared to typical Darlington amplifiers. The SGC4486Z is designed for high linearity 3V gain block applications that require small size and minimal external components. It is internally matched to 50Ω .





Features

- Single Fixed 3V Supply
- No Dropping Resistor Required
- Patented Self-Bias Circuitry
- P_{1dB}=12.7dBm at 1950MHz
- $OIP_3 = 27.5 dBm$ at 1950 MHz
- Robust 1000V ESD, Class 1C HBM

Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS, **WCDMA**
- IF Amplifier
- Wireless Data, Satellite

Parameter	Specification			I locit	Oo un distinue	
	Min.	Тур.	Max.	Unit	Condition	
Small Signal Gain	19.0	20.5	22.0	dB	850MHz	
	13.0	14.5	16.0	dB	1950MHz	
		12.3		dB	2400MHz	
Output Power at 1dB Compression		13.8		dBm	850MHz	
	11.7	12.7		dBm	1950MHz	
		12.4		dBm	2400MHz	
Output Third Order Intercept Point		29.0		dBm	850MHz	
	25.5	27.5		dBm	1950MHz	
		26.5		dBm	2400MHz	
Input Return Loss	10.5	14.5		dB	1950MHz	
Output Return Loss	7.5	11.5		dB	1950MHz	
Noise Figure		3.4	4.4	dB	1930MHz	
Thermal Resistance		145		°C/W	junction - lead	
Device Operating Voltage		3.0		V		
Device Operating Current	46.0	52.0	58.0	mA		

Test Conditions: $V_D = 3V$, $I_D = 52$ mA Typ., OIP_3 Tone Spacing = 1MHz, P_{OUT} per tone = -5dBm, $T_L = 25$ °C, $Z_S = Z_L = 50\Omega$, Bias Tee Data



Absolute Maximum Ratings

Parameter	Rating	Unit
Device Current (I _{CE})	110	mA
Device Voltage (V _{CE})	4	V
RF Input Power* (See Note)	12	dBm
Junction Temp (T _J)	+150	°C
Operating Temp Range (T _L)	-40 to +85	°C
Storage Temp	+150	°C
ESD Rating - Human Body Model (HBM)	Class 1C	
Moisture Sensitivity Level	MSL 1	

^{*}Note: Load condition $Z_L = 50\Omega$

Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EUDirective 2002/95/EC (at time of this document revision).

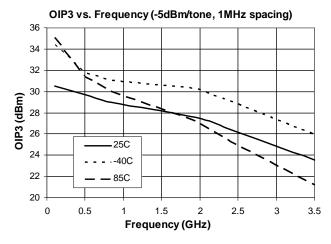
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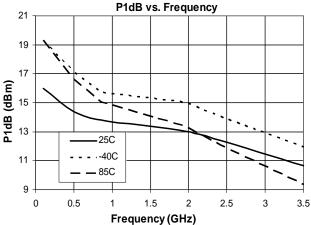
Typical RF Performance with Application Circuit at Key Operating Frequencies (Bias Tee)

Parameter	Unit	100	500	850	1950	2400	3500
		MHz	MHz	MHz	MHz	MHz	MHz
Small Signal Gain (G)	dB	23.5	22.5	20.5	14.5	12.3	9.5
Output Third Order Intercept Point (OIP ₃)	dBm	30.5	29.5	29.0	27.5	26.5	23.5
Output Power at 1dB Compression (P _{1dB})	dBm	16.1	14.4	13.8	12.7	12.4	10.6
Input Return Loss (IRL)	dB	24.0	15.5	16.5	14.5	14.5	13.0
Output Return Loss (ORL)	dB	25.0	17.0	16.5	11.5	12.0	11.0
Reverse Isolation (S ₁₂)	dB	25.0	26.0	25.0	20.5	19.0	17.5
Noise Figure (NF)	dB	2.8	2.8	3.1	3.4	3.9	4.8

Test Conditions: $V_D = 3V$ $I_D = 52 \text{ mA Typ.}$ OIP_3 Tone Spacing = 1 MHz, P_{OUT} per tone = -5 dBm $T_L = 25 \degree C Z_S = Z_L = 50 \Omega$

Typical Performance with Bias Tee, V_D=3V, I_D=52mA





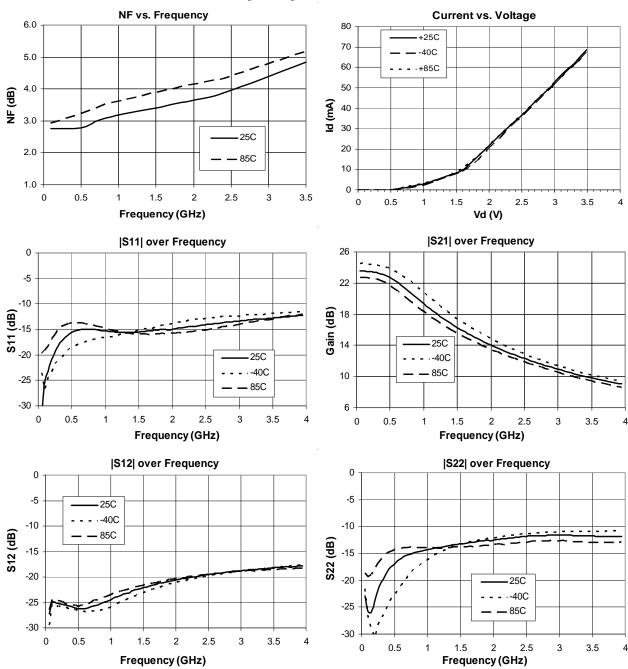
Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

Bias Conditions should also satisfy the following expression:

 $I_DV_D < (T_J - T_L)/R_{TH}$, j-I and $T_L = T_{LEAD}$



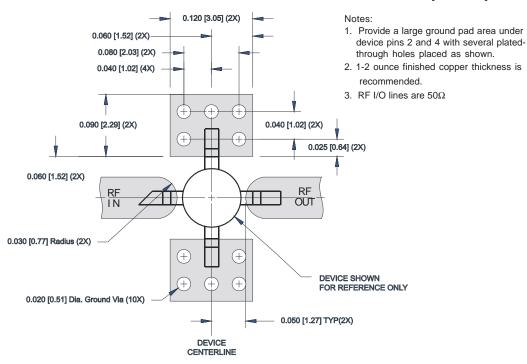
Typical Performance with Bias Tee, $V_D = 3V$, $I_D = 52mA$





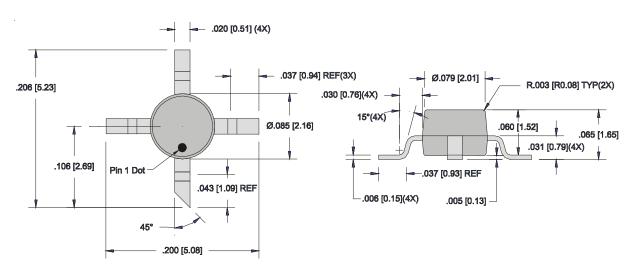
86 PCB Pad Layout

Dimensions in inches [millimeters]



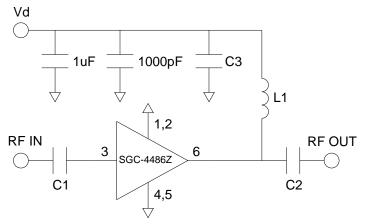
86 Nominal Package Drawing

Dimensions in inches (millimeters)
Refer to drawing posted at www.rfmd.com for tolerances.



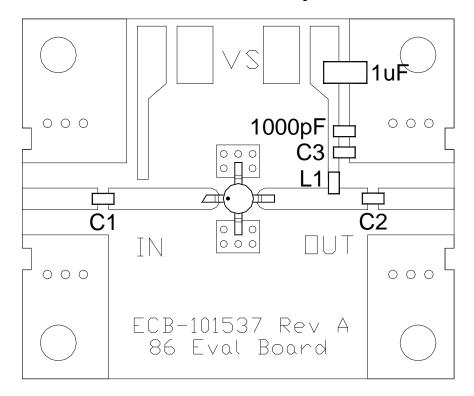


Application Schematic



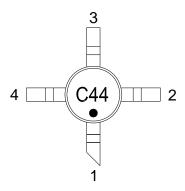
Application Circuit Element Values				
Reference Designator	100-2000MHz	2000-4000MHz		
C1	1000pF	2.7pF		
C2	100pF	6.8pF		
С3	100pF	6.8pF		
L1	120nH	39nH		

Evaluation Board Layout





Part Identification



Ordering Information

Ordering Code	Description
SGC4486Z	13" Reel with 3000 pieces
SGC4486ZSQ	Sample bag with 25 pieces
SGC4486ZSR	7" Reel with 100 pieces
SGC4486ZPCK1	100 MHz to 2000 MHz PCBA with 5-piece sample bag
SGC4486ZPCK2	2000 MHz to 4000 MHz PCBA with 5-piece sample bag